

## BAW56/BAV70/BAV99

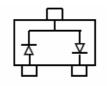
SWITCHING DIODE

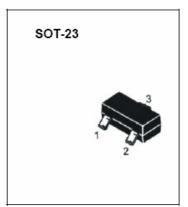
#### **FEATURES**

- Fast Switching Speed
- For General Purpose Switching Applications
- High Conductance









BAW56 Marking: A1

BAV70 Marking: A4

BAV99 Marking: A7

Maximum Ratings @T<sub>A</sub>=25℃

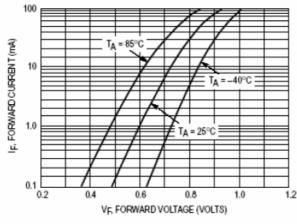
| Parameter                                  | Symbol                 | Limits  | Unit |
|--|------------------------|---------|------|
| Reverse voltage                            | V <sub>R</sub>         | 70      | ٧    |
| Forward Current                            | I <sub>F</sub>         | 200     | mA   |
| Peak Forward Surge Current                 | I <sub>FM(surge)</sub> | 500     | mA   |
| Power Dissipation                          | P₀                     | 225     | mW   |
| Thermal Resistance Junction to Ambient Air | R <sub>eJA</sub>       | 556     | °C/W |
| Junction temperature                       | TJ                     | 150     | ℃    |
| Storage temperature range                  | T <sub>STG</sub>       | -55-150 | ℃    |

### Electrical Characteristics @T<sub>A</sub>=25℃

| Parameter                     | Symbol          | Min. | Тур. | Max.  | Unit | Conditions  |
|-------------------------------|-----------------|------|------|-------|------|---|
| Reverse Breakdown Voltage     | V <sub>R</sub>  | 70   |      |       | ٧    | I <sub>R</sub> =100μA                             |
| Forward voltage               | V <sub>F1</sub> |      |      | 0.715 | ٧    | I <sub>F</sub> =1mA                               |
|                               | V <sub>F2</sub> |      |      | 0.855 | ٧    | I <sub>F</sub> =10mA                              |
|                               | V <sub>F3</sub> |      |      | 1     | ٧    | I <sub>F</sub> =50mA                              |
|                               | V <sub>F4</sub> |      |      | 1.25  | ٧    | I <sub>F</sub> =150mA                             |
| Reverse current               | I <sub>R</sub>  |      |      | 2.5   | μΑ   | V <sub>R</sub> =70V                               |
| Capacitance between terminals | Ст              |      |      | 1.5   | pF   | V <sub>R</sub> =0,f=1MHz                          |
| Reverse recovery time         | trr             |      |      | 6     | ns   | I <sub>F</sub> = I <sub>R</sub> = 10mA,           |
|                               |                 |      |      |       |      | Irr= 0.1 x I <sub>R</sub> , R <sub>L</sub> = 100Ω |

# **Typical Characteristics**

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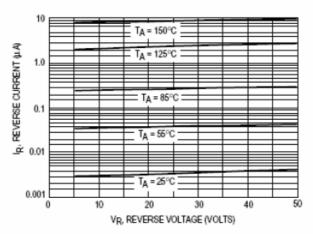


Figure 2 Leakage Current

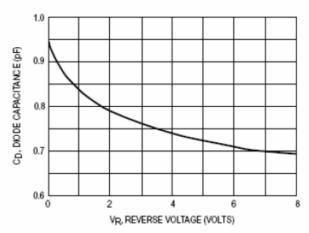


Figure 3 Capacitance

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